

# Designing and Characterizing the laser system

Triveni Rao, USPAS 2013, Duke  
University

# First things first

## ➤ Determine the operating parameters:

- Wavelength
- Pulse duration
- Energy/power
- Pulse structure
- Synchronization
- Beam quality
- Polarization
- Stability
  - Energy
  - Pulse duration
  - Timing
  - Direction
- Pre/post pulse energy

## ➤ Safety

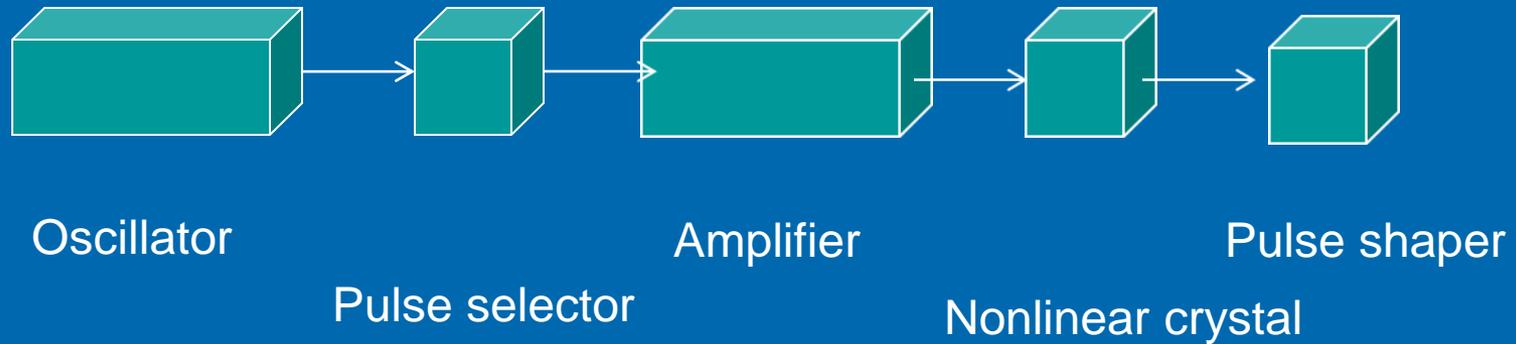
## ➤ Infra-structure

- Power
- Water
- Temperature control
- Humidity control
- Particulate control
- Vibration

## ➤ Data collection

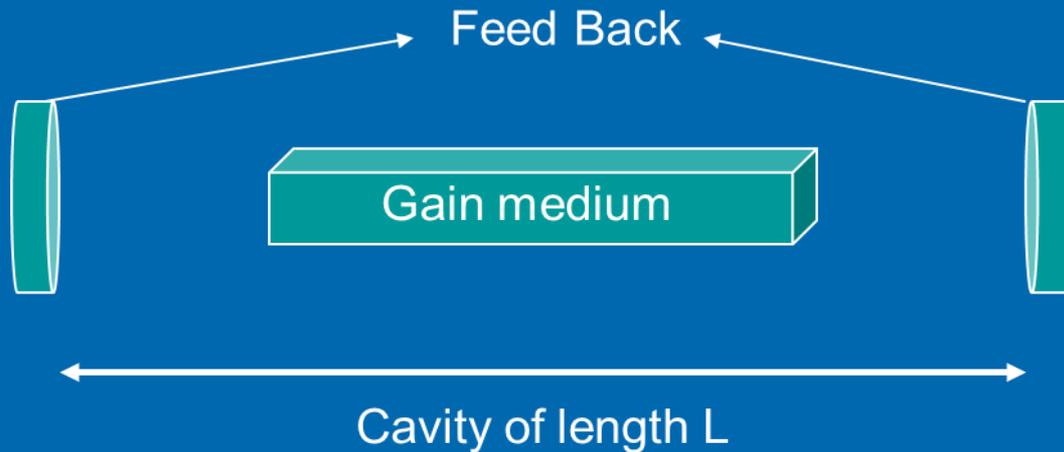
## ➤ Parameter control

# Typical Laser System



Based on Requirements, each of these components (+ a few others) have to be defined

# Laser Oscillator



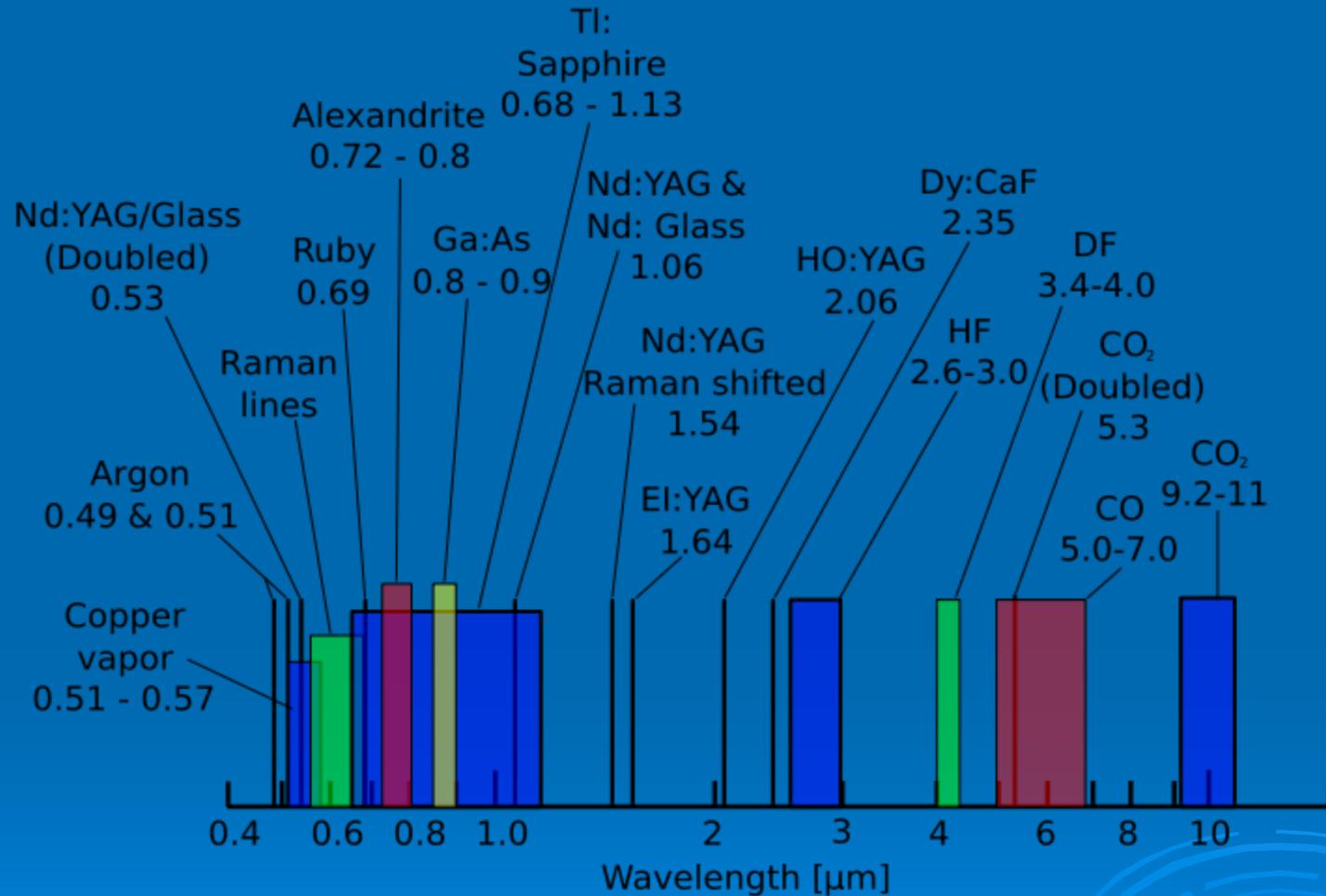
Consists of  
Gain medium-Energized by pumping source  
Cavity mirrors  
Synchronizing elements

Gain medium determines:  
Fundamental wavelength  
Minimum pulse duration  
Maximum storable energy

Cavity configuration determines:  
Repetition rate  
Synchronism  
Max extractable power  
Pulse duration  
Transverse parameters  
Maximum extractable energy

Pump Source determines:  
Pulse repetition rate  
Maximum stored energy

# Wavelength



Most Commonly used: Nd family, Ti: Sapphire, CO<sub>2</sub>

# Properties of most common Bulk Solid State Laser Gain Media

Host	Dopant	Wavelength (μm)	Band Width (nm)	Gain Cross Section ( $\times 10^{-20}$ cm <sup>2</sup> )	Upper State Lifetime (μs)
YAG	Nd	1.064	0.6	33	230
YLF	Nd	1.047-1.0530	1.2	18	480
Vanadate	Nd		0.8	300	100
Phosphate Glass	Nd	1.0535-1.054	24.3	4.5	323
KGW	Yb	1.026	25	2.8	250
YAG	Yb	1.030	6.3	2.0	950
Phosphate Glass	Yb	1.06-1.12	62	0.049	1 300
Sapphire	Ti	0.790	230	41	3.2

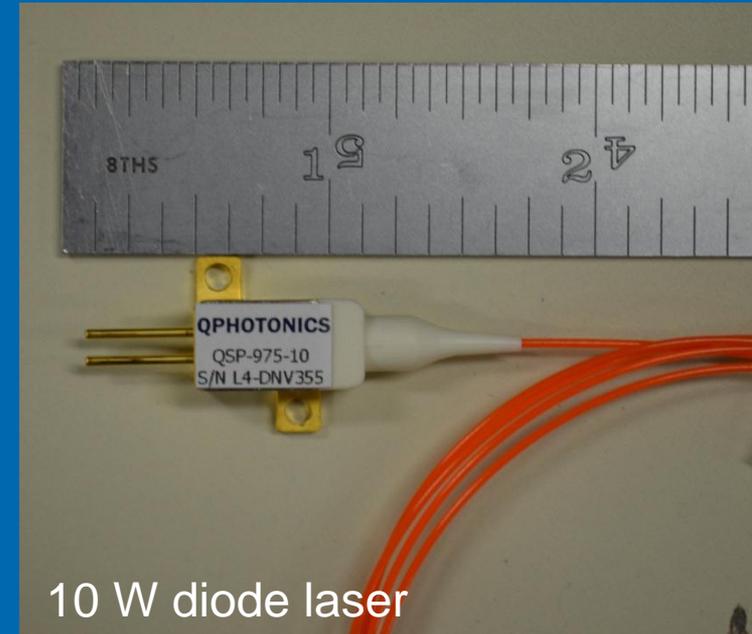
Pulse duration

E. Wolf, Ed., *Progress in Optics*, Vol. 34, Amsterdam: Elsevier Science, 2004

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# Pump Sources

- Arc Lamp-CW laser
- Flash lamp-Pulsed laser
- Electron beam
- Electric discharge
- Diode-CW and pulsed
  - High efficiency
  - Current or voltage modulation
  - Scalable to high energy/power
  - Compact
  - Fiber coupled



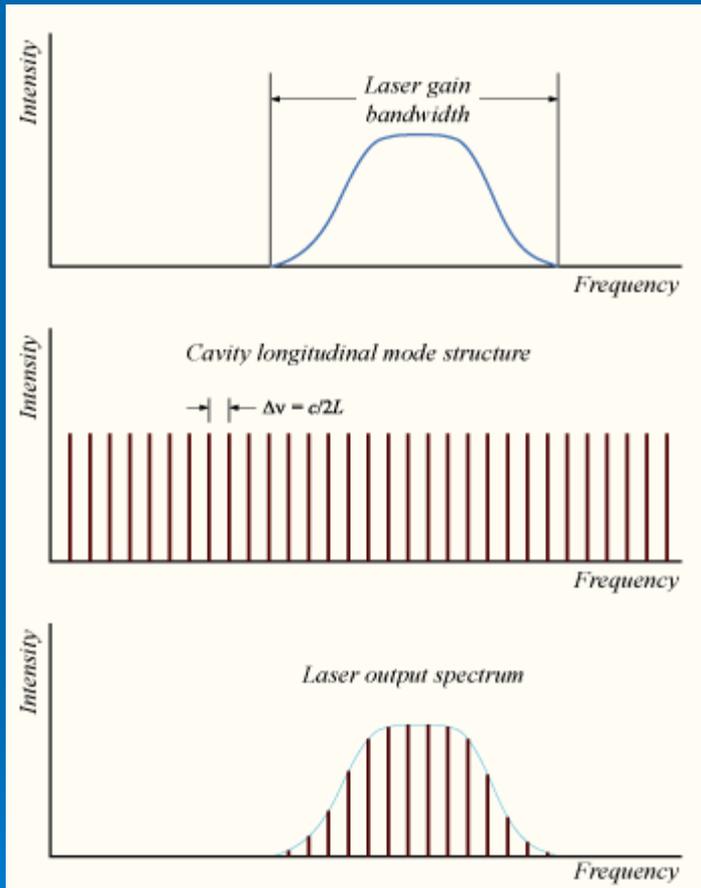
# How to get pulses?

## ➤ Change the Q of the cavity:

- Sudden change in gain
  - Pulse pumping (Flash lamp, e beam, electric discharge)
- Sudden change in loss
  - Q switching
  - **Mode-locking**
    - Active mode-locking - AO/EO modulator
    - Passive mode locking- Saturable absorber( intensity dependent absorption), Kerr lens (Intensity dependent focusing)

## ➤ Modulating the pump laser diode pump

# Mode locking

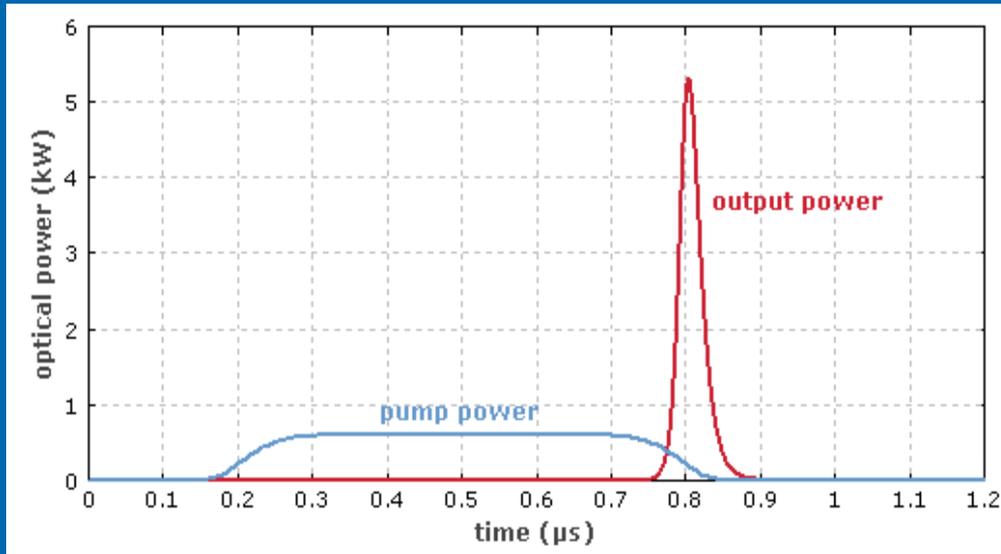


Youtube video:  
Principles of mode-locking-  
passively mode-locked lasers

<http://www.youtube.com/watch?v=efxFduO2YI8>

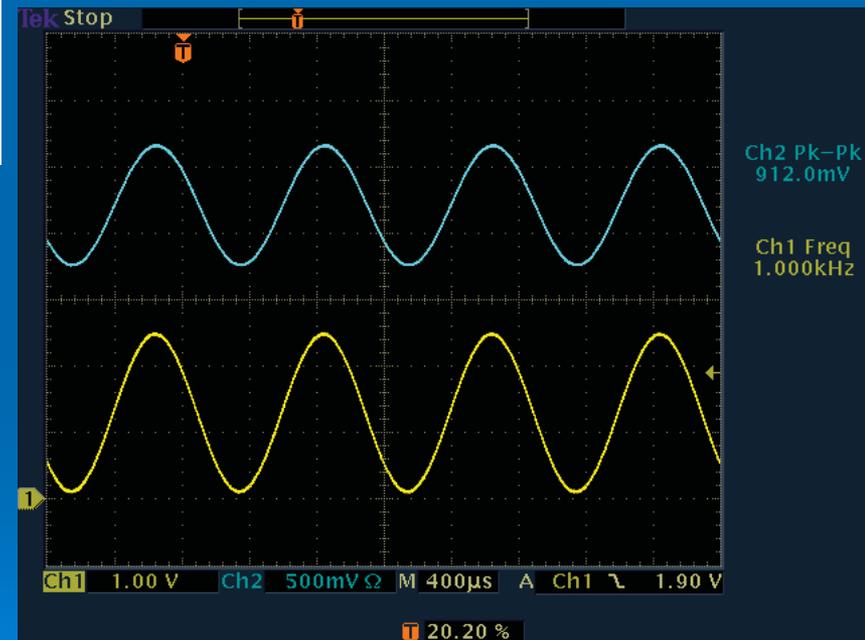
<http://upload.wikimedia.org/wikipedia/commons/c/ca/Modelock-1.png>

# Gain switching in diode laser



[http://www.rp-photonics.com/gain\\_switching.html](http://www.rp-photonics.com/gain_switching.html)

<http://www.ilxlightwave.com/appnotes/AN%2022%20REV01%20Modulating%20Laser%20Diodes.pdf>



Current modulation of the power supply

# Amplifier

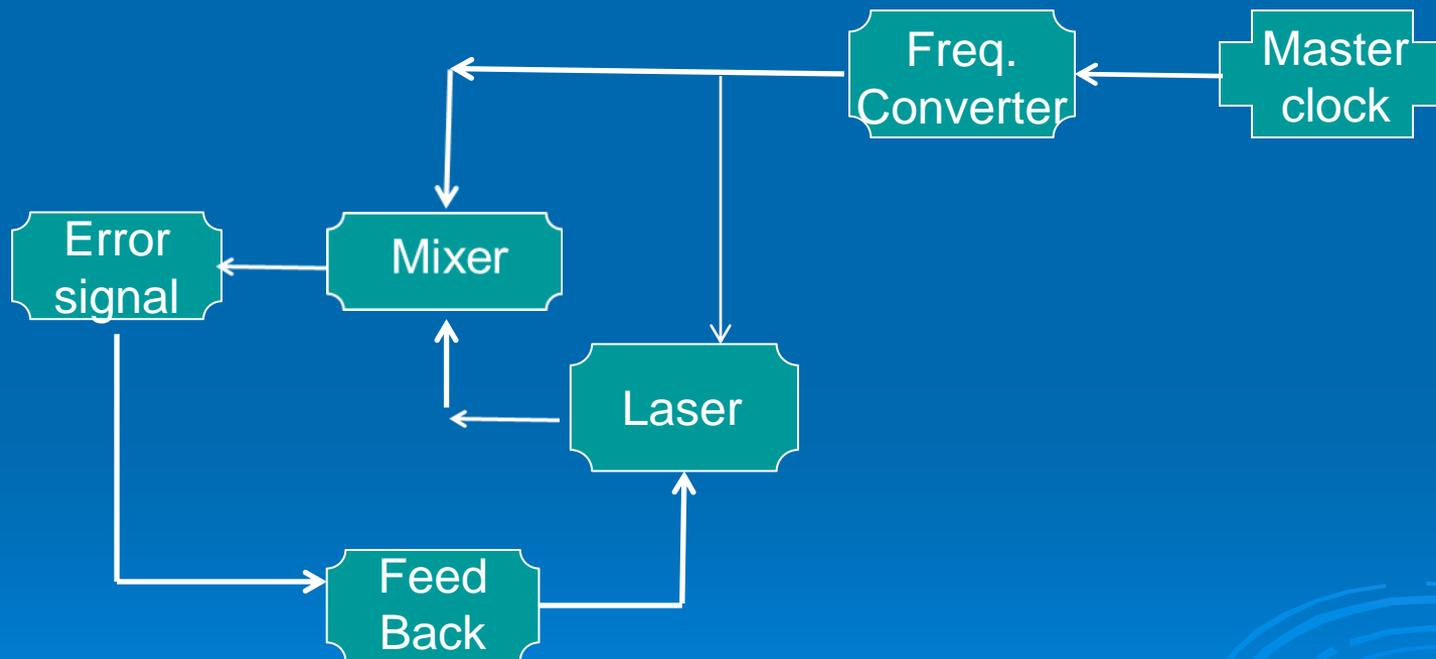
- Determine Number of stages
  - Required amplification
  - S/N Ratio
- Determine amplifier configuration:
  - Regenerative
    - Good transverse mode quality, Multiple passes
    - Higher noise, optical damage
  - Multipass
    - Scalable, higher energy/power
    - Poor mode quality, larger fluctuation

# Pulse selection

- Choose the process
  - (eg. Pockell's cell)
- Choose the hardware
  - S/N
  - Damage threshold
  - Operating conditions (temp. etc)
- Choose the location
  - After oscillator, amplifier, harmonic crystals

# Synchronization

Need to synchronize laser pulse to other pulses: electron, RF, other lasers etc.



# Diagnostics

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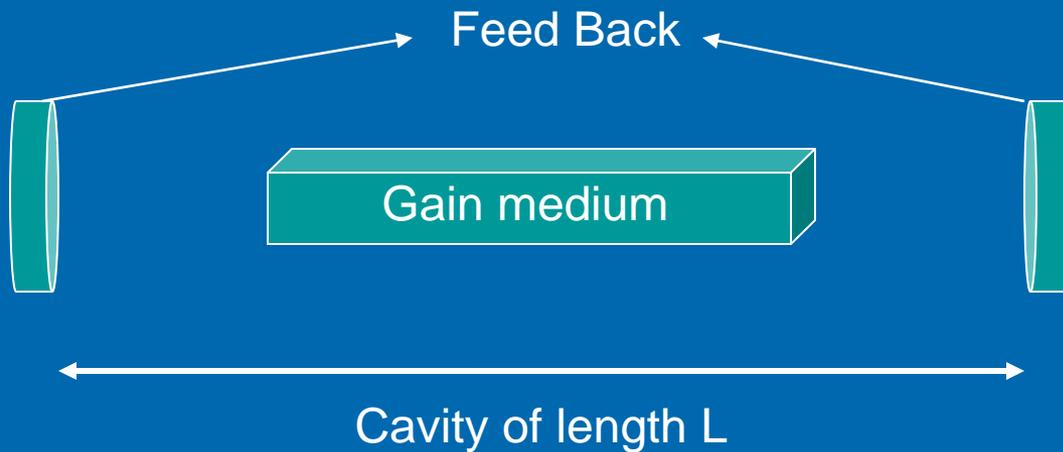


# Energy, Power

- Energy, Power: energy meter, power meter
- Pulse to Pulse Stability: Photodiode
- Online Monitoring: Calibrated photodiode
- Droop correction: Calibrated photodiode+ feedback/feed forward

# Spatial distribution

- Profile
- Spot size
- stability



Cavity supports transverse (spatial profile) and longitudinal (frequency spectrum) modes

The electric field  $\vec{E}$  is given by 
$$\vec{E}(r, z, t) = \vec{E}(r, t) e^{i(k\vec{n} \cdot \vec{r} - \omega t)}$$

Time averaged Energy flux  $S$  is given by

$$S = \frac{c}{8\pi} \sqrt{\frac{\epsilon}{\mu}} |\vec{E}|^2 \vec{n}$$

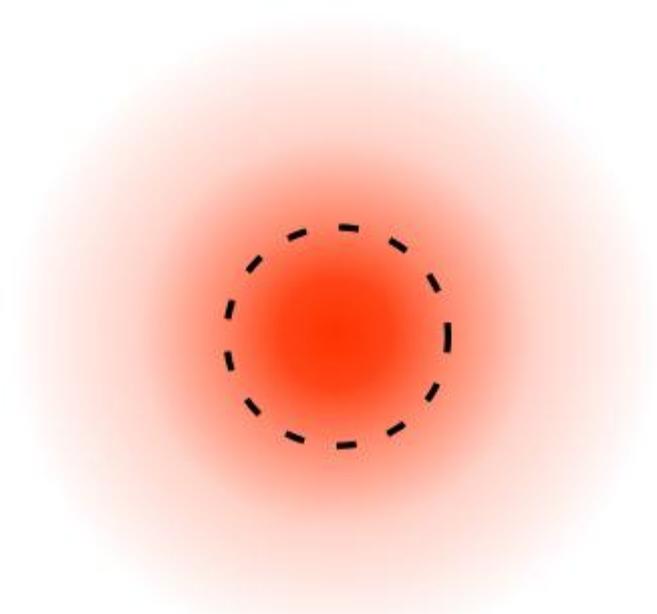
# Transverse Profile $E(r)$

Limiting to lowest order mode,

$$E(r) = E_0 e^{-\left(\frac{r}{w}\right)^2}$$

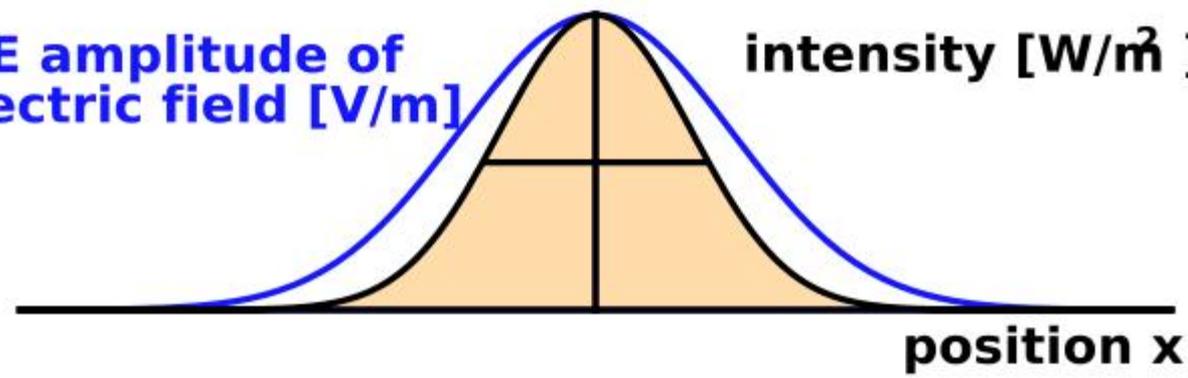
$$I(r) = I_0 e^{-\left(\frac{2r^2}{w^2}\right)}$$

Gaussian Intensity profile!



**E amplitude of electric field [V/m]**

**intensity [W/m<sup>2</sup>]**



**position x**

# Important Parameters/Equations of Gaussian Beam

- The parameter  $w$  is called the beam radius within which 86.5% of the total power of the Gaussian beam is contained.
- The spot size at any axial distance  $z$  from beam waist  $w_0$  can be calculated using

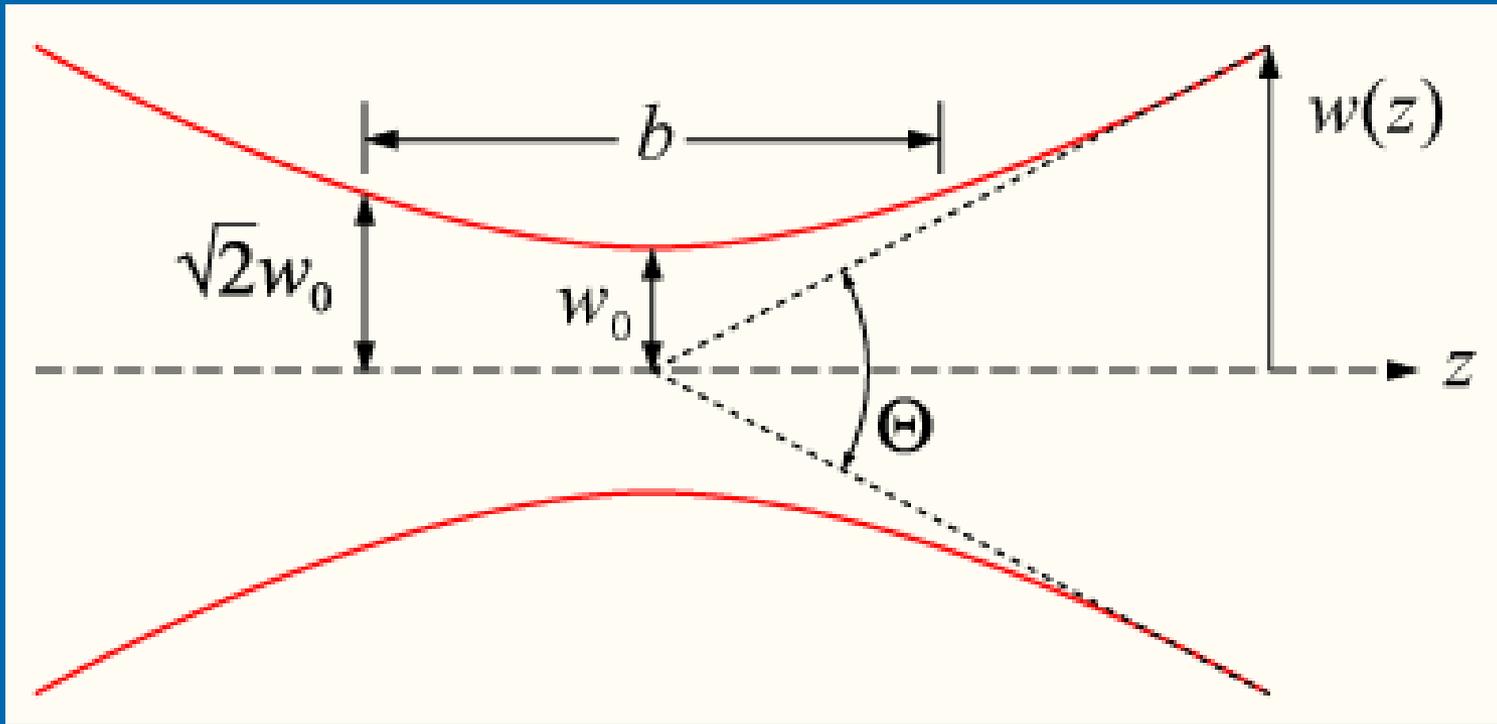
$$w(z) = w_0 \left\{ 1 + \left( \frac{\lambda z}{\pi w_0^2} \right)^2 \right\}^{\frac{1}{2}}$$

- The full divergence angle  $\theta$  is given by

$$\theta = 1.27 \frac{\lambda}{(2w_0)}$$

- The confocal parameter  $b$ , the distance between points on either side of the beam waist for which the spot size  $w(z) = \sqrt{2}w_0$  and the region over which the phase front is nearly planar, is given by

$$b = \frac{2\pi w_0^2}{\lambda}$$



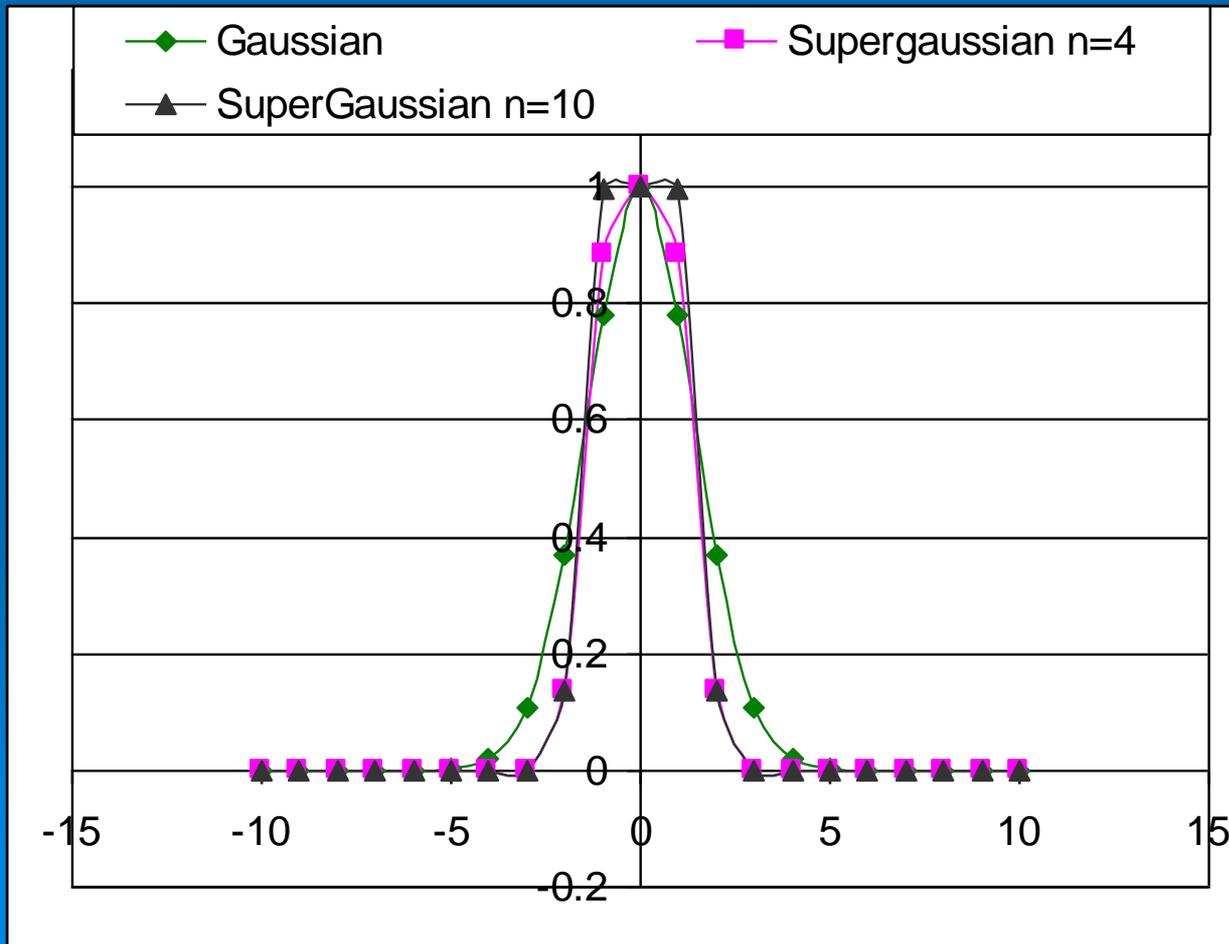
Typical commercial lasers have outputs that are nearly Gaussian, but not exactly. The extent to which they approach Gaussian is given by the  $m$  parameter

$$m = \frac{w_{\text{laser}}}{w_{\text{gaussian}}}$$



# Supergaussian (Flat Top) Intensity Profile

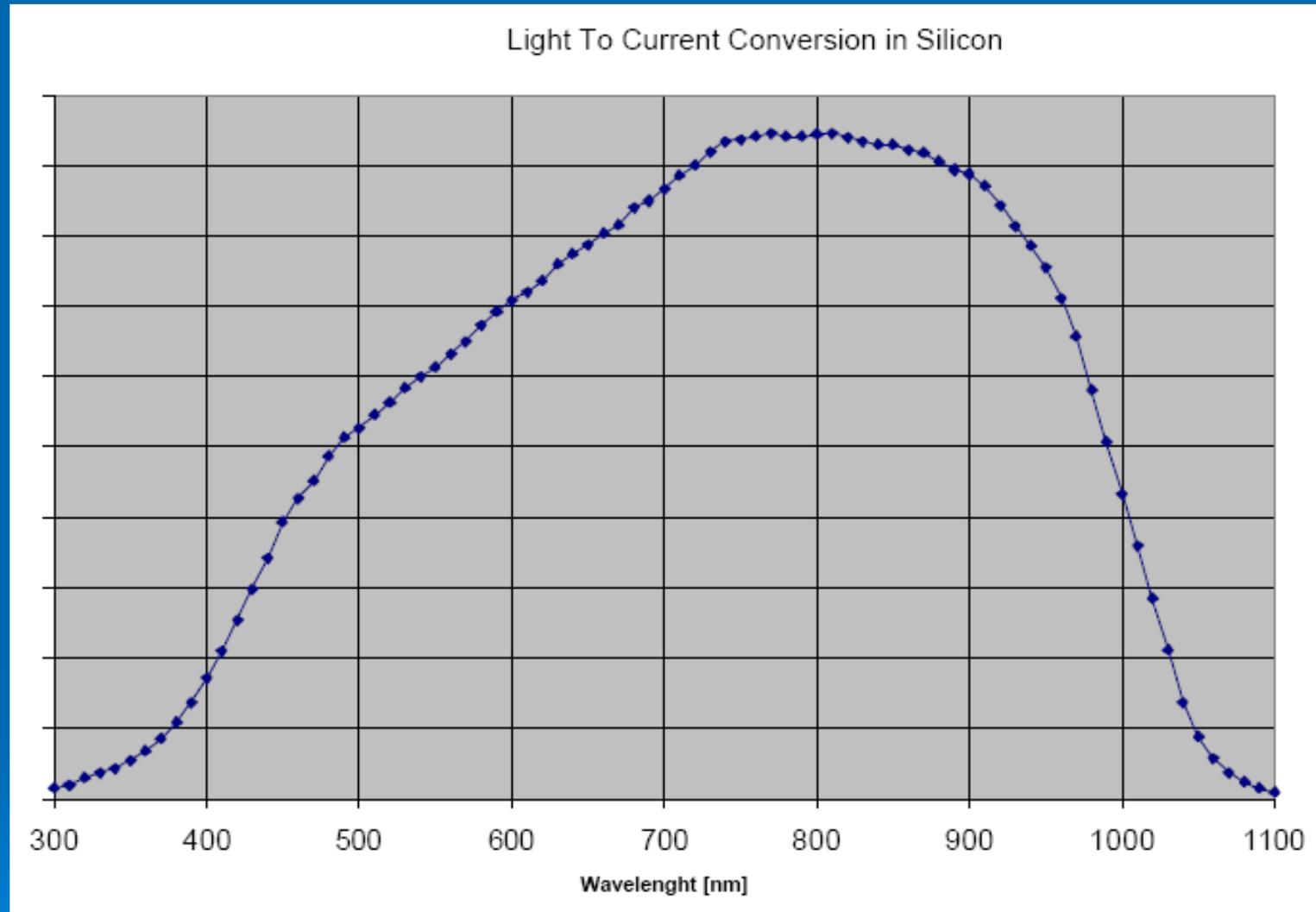
➤  $I(r) = I_0 e^{-2\left(\frac{r}{w}\right)^n}$   $n > 2$



# Measurement Techniques for Transverse Profile

Technique	Advantage	Disadvant.	Application
CCD	Direct Ease of measurements w/algorithms Good resolution	Dynamic range Long/short wavelength sensitivity	On line beam diagnostics
Slit scan	Inexpensive	Poor resolution Multi-shot Data analysis	Low cost beam diagnostics
Video camera	Multiple displays Inexpensive	Poor resolution Data analysis	Monitoring, aligning

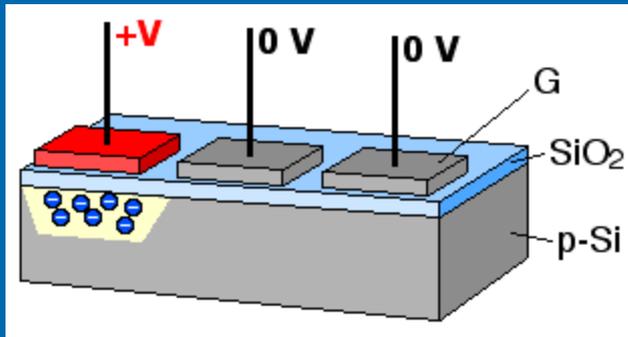
# Photosensitive material



IR: Ge response curve 0.8-1.8 micron. HgCdT 1-12 micron (Cryo cooled)

UV: Fluorescence

# Principle of CCD



[http://en.wikipedia.org/wiki/Charge-coupled\\_device](http://en.wikipedia.org/wiki/Charge-coupled_device)

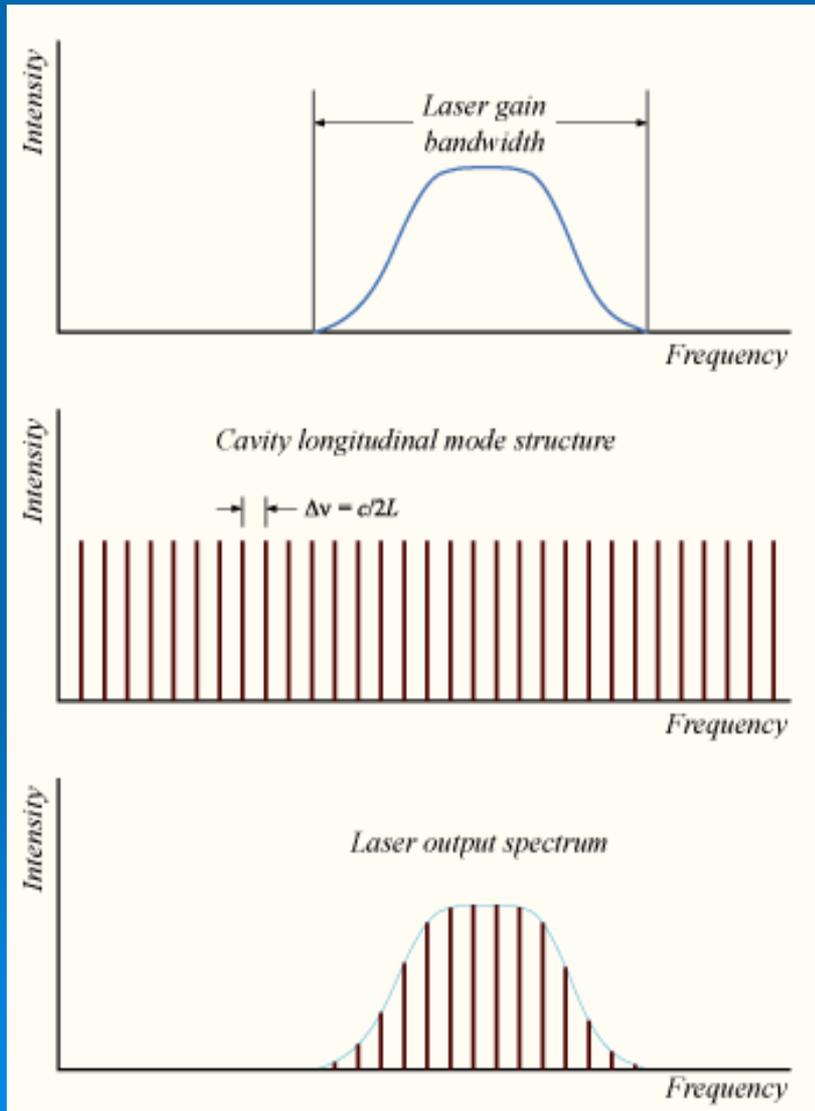
Video

<http://nofilmschool.com/2012/06/ever-wondered-how-a-ccd-sensor-works/>

# Selection Criteria

- Sensor and array:
  - Wavelength
  - Size and resolution
  - Dynamic Range
- Software:
  - Parameters required
  - Theory behind software

# Longitudinal modes-Spectral Content, Pulse Duration



The pulse duration of the laser beam is dictated by a number of factors

- Storage time (upper state life time) of the lasing medium
- Bandwidth of the lasing line
- Pump duration
- Design of the cavity elements, their linear and nonlinear dispersion

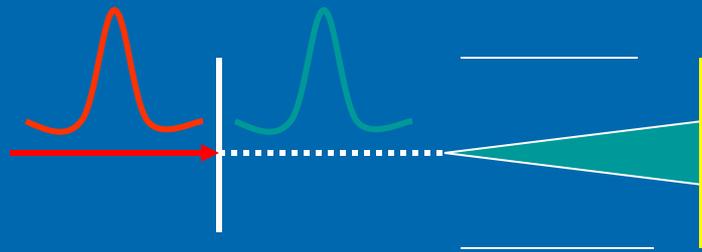
Minimum Pulse duration for Gaussian profile is

$$\Delta t = \frac{0.44}{N \Delta\nu}$$

# Measurement Techniques for Longitudinal (temporal) profile

Technique	Advantage	Disadvant.	Application
Photodiode, phototube	Direct Inexpensive Sensitive Linear simple	Bandwidth limited	ns, subns pulses
Streak camera	Direct Vis-UV	Expensive Complicated	Few ps
Auto/cross correlator Single, multi shot	Moderately inexpensive	Indirect Insensitive to assymetry	ps, fs
Spectral domain measurements	Complete characterization	Complicated	fs

# Streak Camera Principle



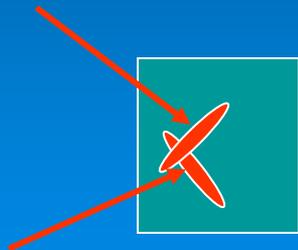
Laser spot size, intensity: Space charge Vs s/n

Synchronization

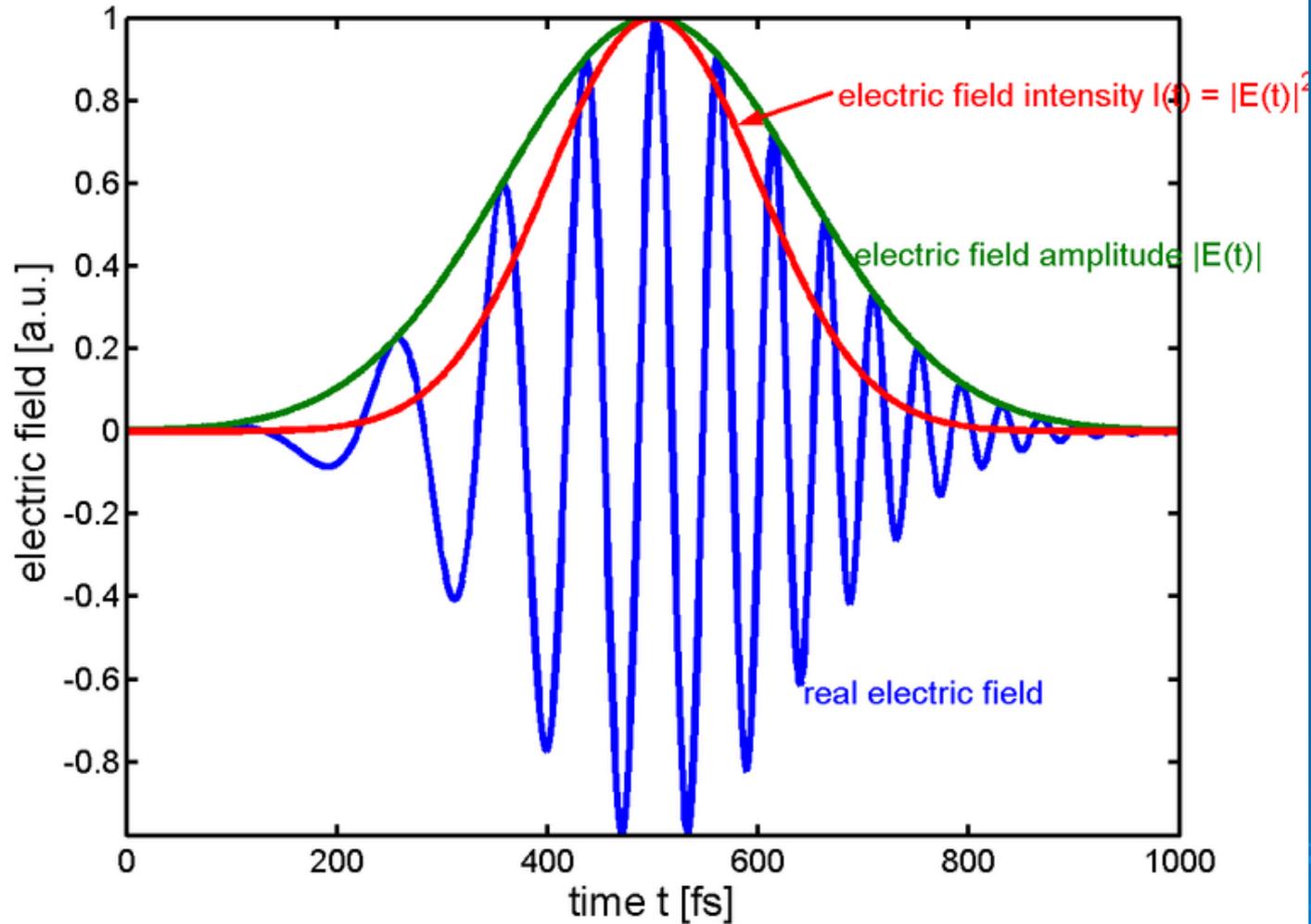
# Autocorrelator Principle



Single shot



Ultra short pulses may not be transform limited: Need to measure amplitude and phase simultaneously



$$E(t) = \sqrt{I(t)} e^{i\omega_0 t} e^{i\psi(t)}$$

$$E(\omega) = \mathcal{F}(E(t))$$

$$E(\omega) = \sqrt{S(\omega)} e^{i\phi(\omega)}$$

$\Psi(t)$ : Phase function

$\Phi(\omega)$ : spectral phase

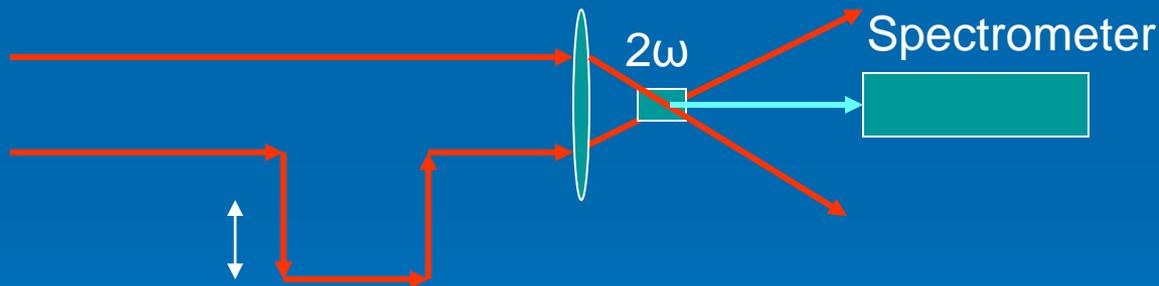
# Characterizing fs pulses

$$E(t) = \sqrt{I(t)}e^{i\omega_0 t} e^{i\psi(t)}$$

$$E(\omega) = \sqrt{S(\omega)}e^{i\phi(\omega)}$$

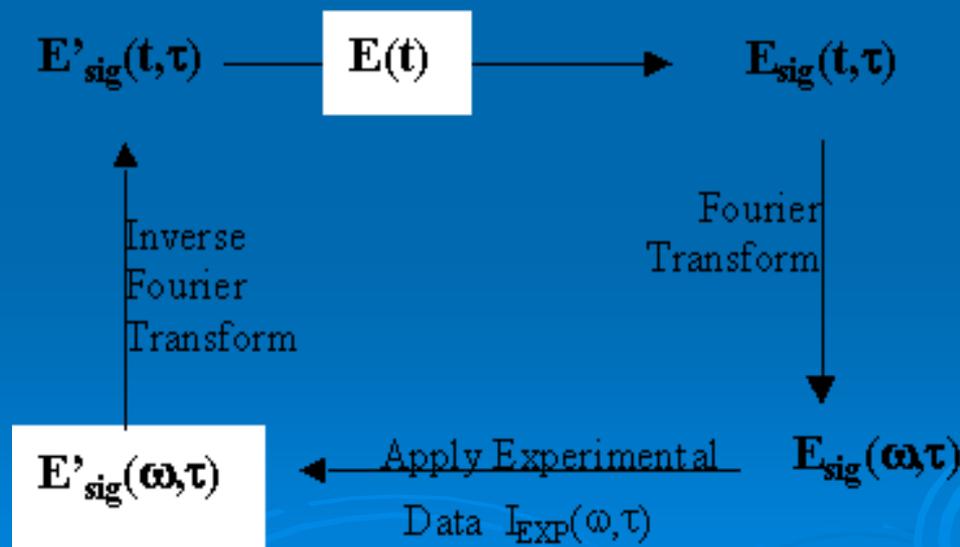
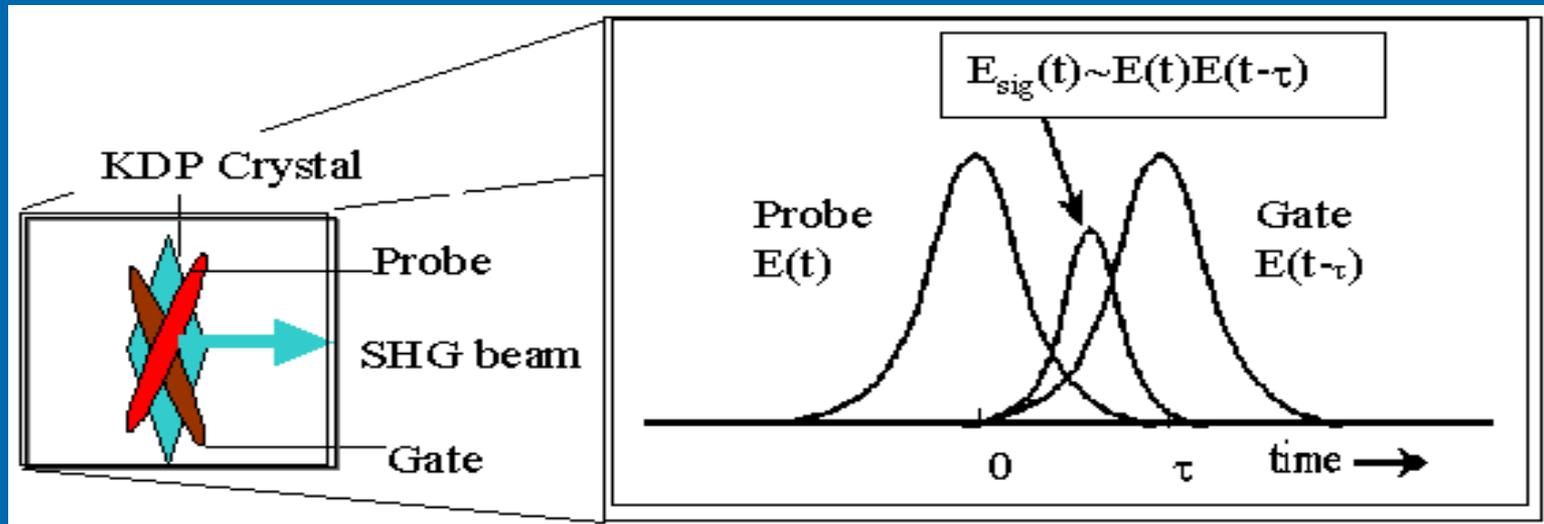
Need to measure both spectrum and spectral phase simultaneously

FROG: Frequency Resolved Optical Gating

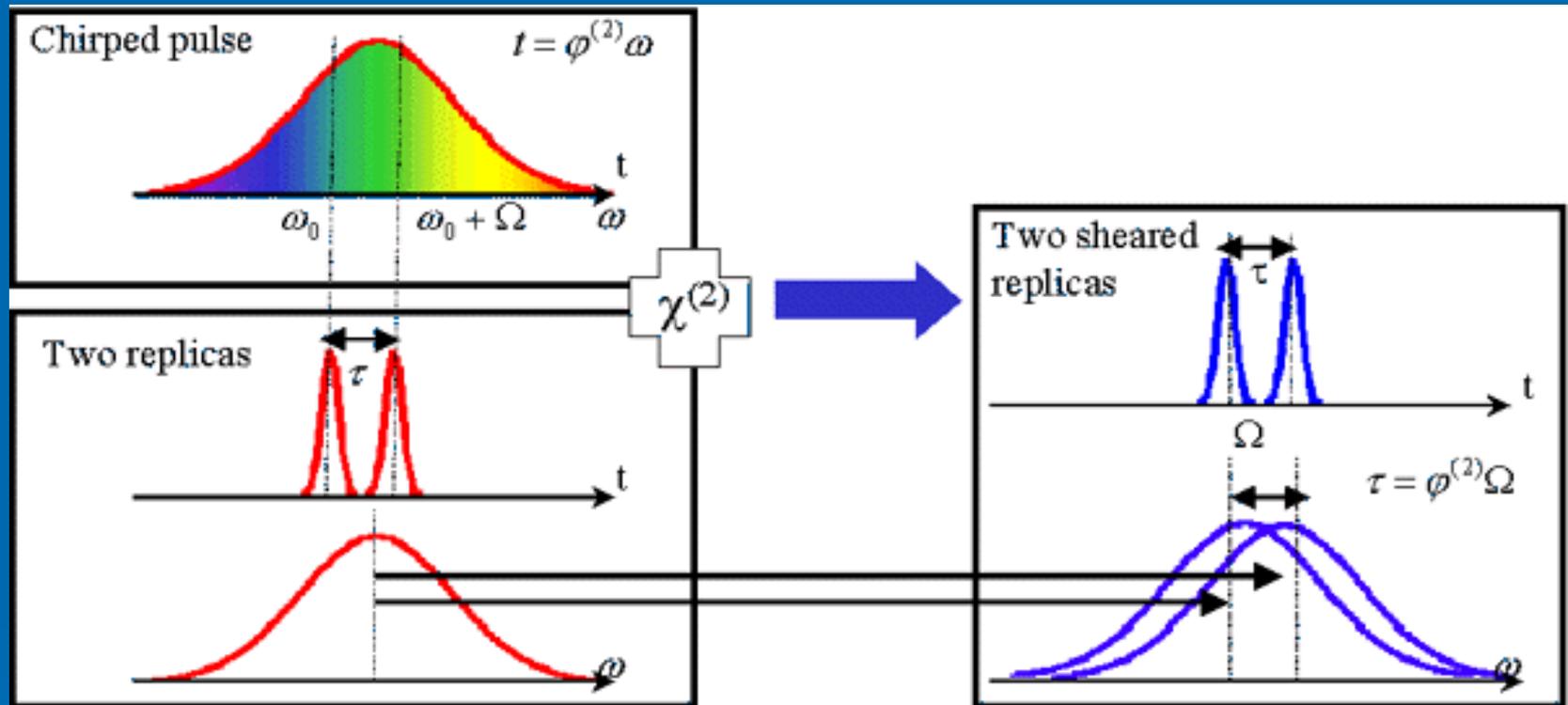


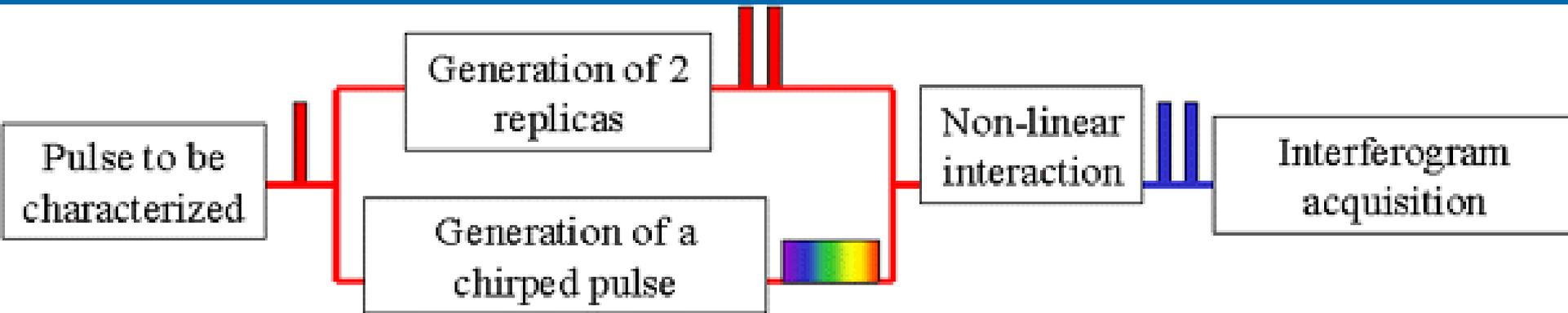
Most commonly used technique

GRENOUILLE: (Grating eliminated no-nonsense Observation of Ultrafast laser light e-fields) simplified device based on SHG FROG-Thick SHG crystal for  $2\omega$  and spectrometer, Fresnel biprism for beam splitter, delay line and beam recombination



# SPIDER: Spectral Phase Interferometry for Direct Electric field Reconstruction





The interference of the two fields is given by

$$\tilde{S}(\omega) = \tilde{I}(\omega) + \tilde{I}(\omega + \Omega) + 2\sqrt{\tilde{I}(\omega)}\sqrt{\tilde{I}(\omega + \Omega)} \cos(\phi(\omega) - \phi(\omega + \Omega))$$

where  $\tilde{E}(\omega) = \sqrt{\tilde{I}(\omega)}e^{i\phi(\omega)}$

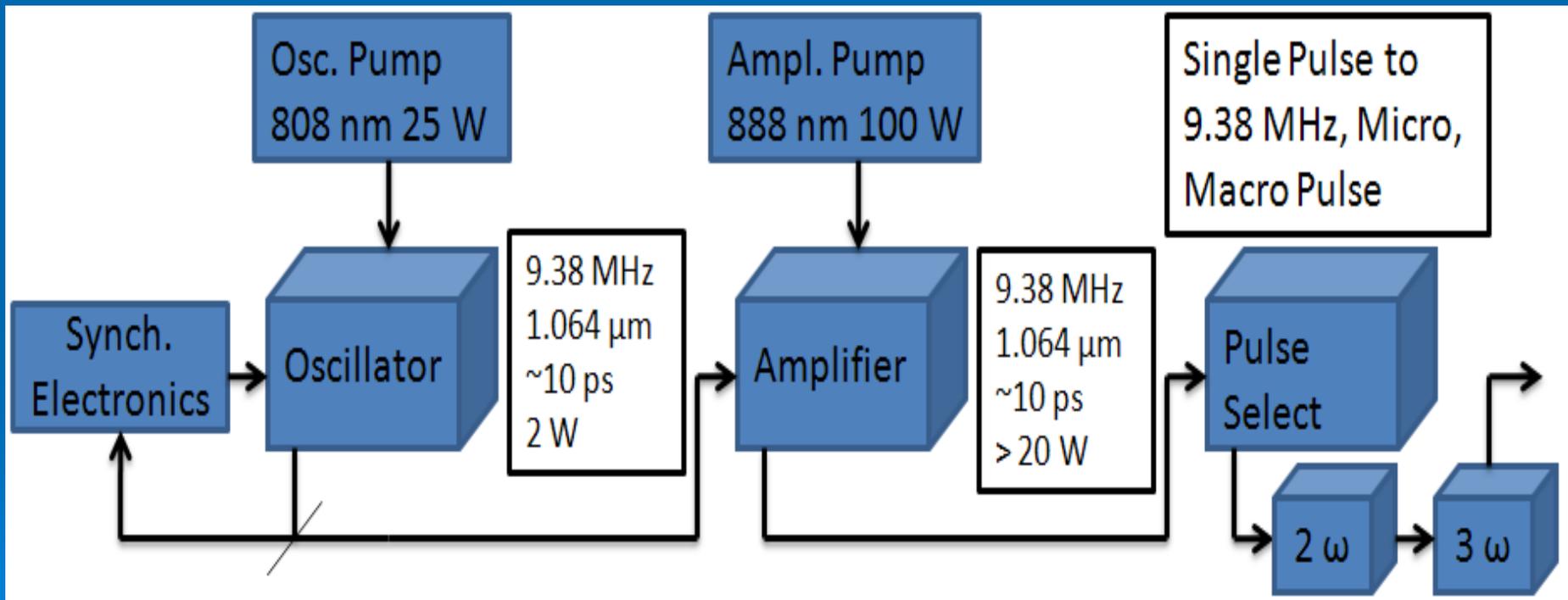
Use Algorithms to extract the phase information

# Other Design Criteria

- Beam transport from laser to interaction region
  - Simulation codes (eg., Zemax)
  - Remote manipulation, vacuum transport
  - Radiation considerations (fiber transport)
- Computer system and platform
  - Data collection
  - Parameter control
- Environmental control
  - Temperature
  - Humidity
  - Dust
- Safety
  - Interlock, entry

# Example

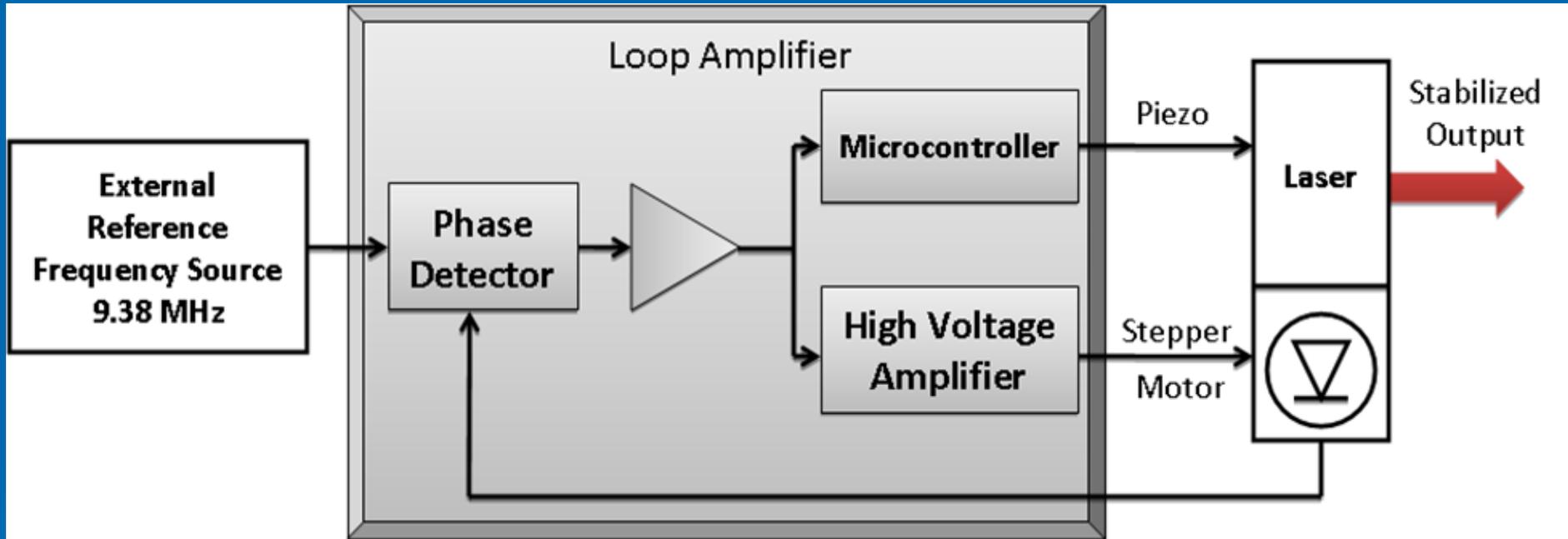
- BNL ERL laser: Commercial, custom unit from Lumera for illuminating photocathode



# Oscillator

- Gain medium: Nd vanadate
- Pump: 18 W fiber coupled 808 nm diode laser
- Mode-Locking: Passive Saturable absorber
- Cavity: Folded cavity w/ resonator length of 16 m
- Synchronization: Piezo-driven mirror in cavity

# Synchronization



# Amplifier

- Gain Medium: Nd: vanadate
- Pump: 100 W diode laser at 888 nm (lower absorption, uniform longitudinal pumping)
- # of passes: 2, polarization rotation between passes
- Entire pulse train amplified

# Pulse selector

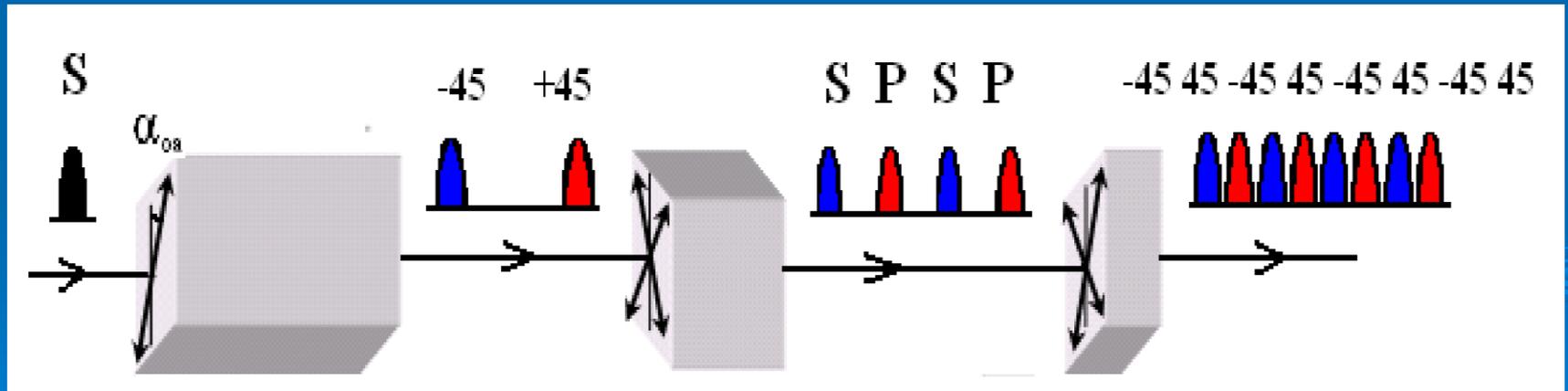
- Method: Pockel's cell, pulse picked when voltage on
- Material: BBO
- Pulse train structure: Micro and macro pulse,
  - macro pulse length adjustable from tens of ns to 100  $\mu$ s,
  - PRF from on demand to 10 kHz
  - # of pulses in macro pulse adjustable from 1 to CW

# Harmonic Crystal

- 1064 nm to 532 nm:
  - LBO, non-critically phase matched, 150 C
  - 50 % efficiency- 10 W
- To 355 nm:
  - LBO, non-critically phase matched, 40 C
  - Green to UV efficiency 50 %- 5W

# Pulse Shaping

- Spatial: Commercial pi shaper
- Temporal: Beam stacking
  - 3 YVO<sub>4</sub> crystals of length 6, 12 and 24 mm



# Diagnostics

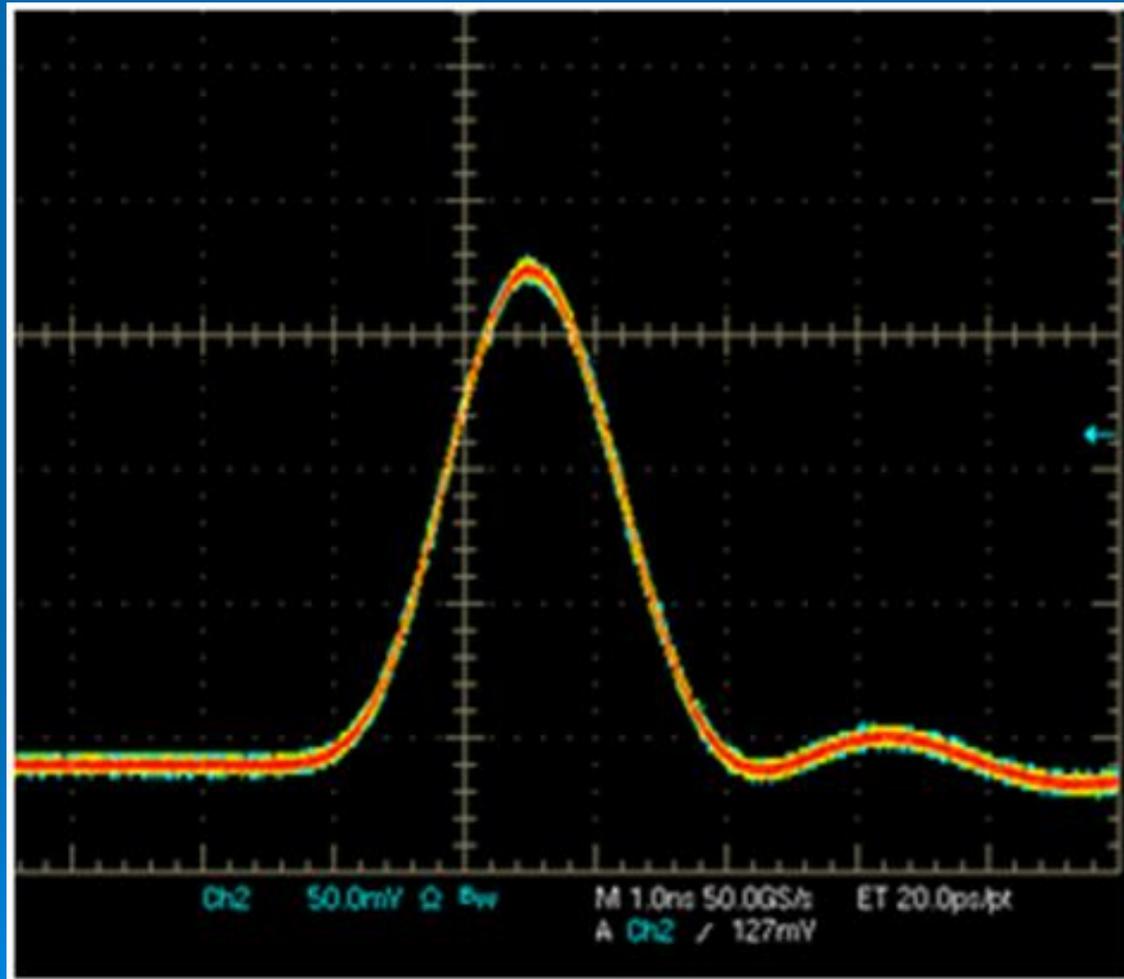
## ➤ On-line:

- Pulse energy and stability-Calibrated Photodiode
- Beam profile-Video camera
- Pointing stability-Video camera

## ➤ Performance:

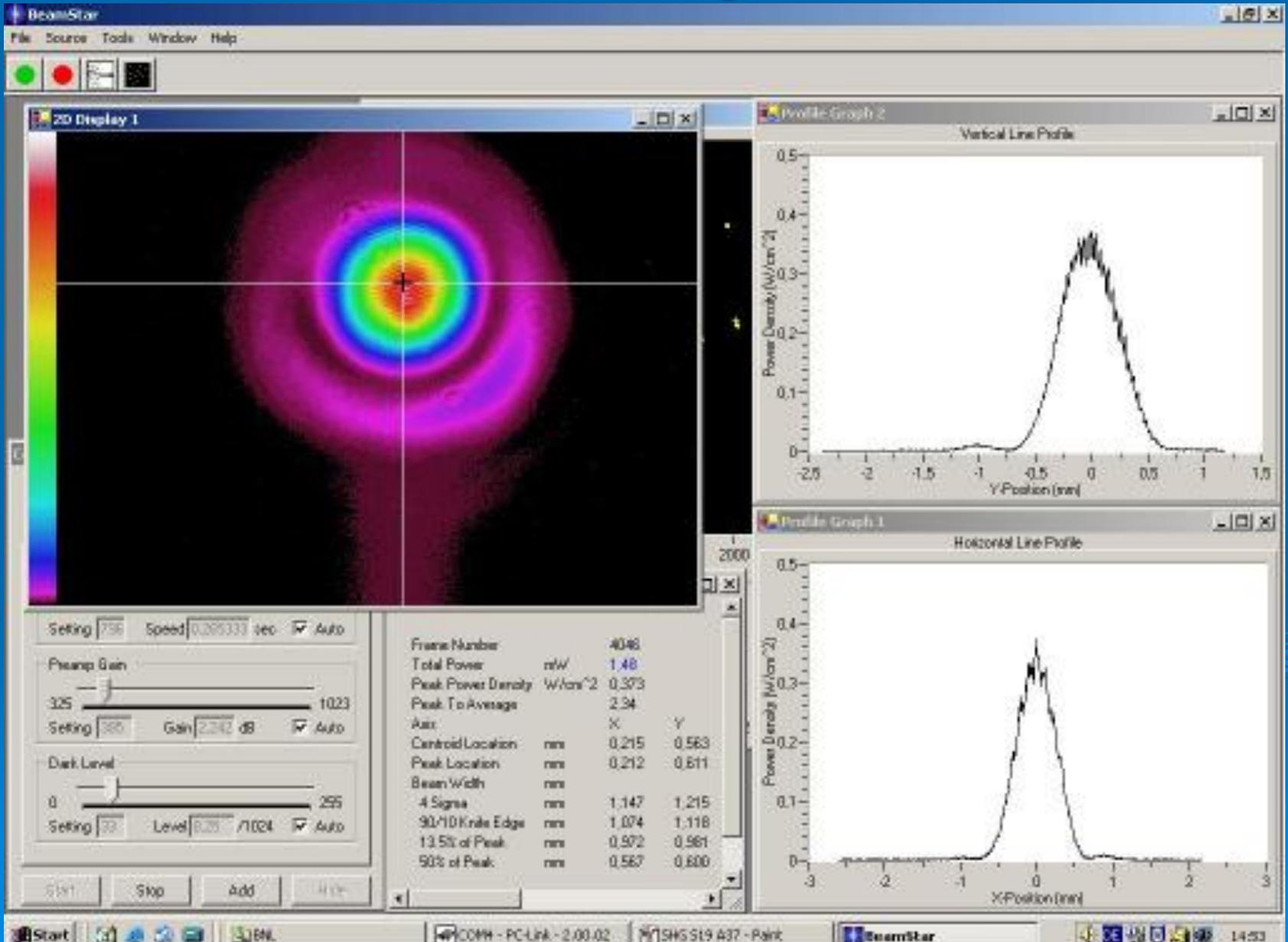
- Pulse energy: energy meter
- Beam profile, pointing stability: CCD
- Pulse duration in IR: Autocorrelator
- Pulse picker, S/N: Photodiode

# Energy and energy stability

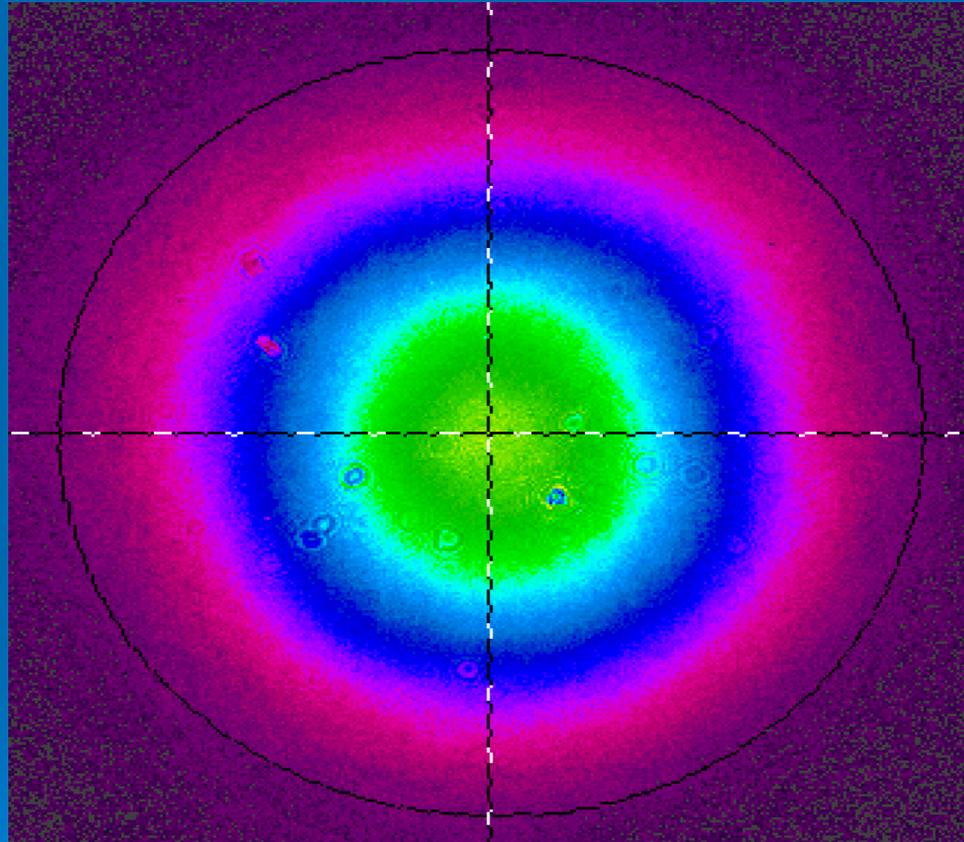


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# IR image



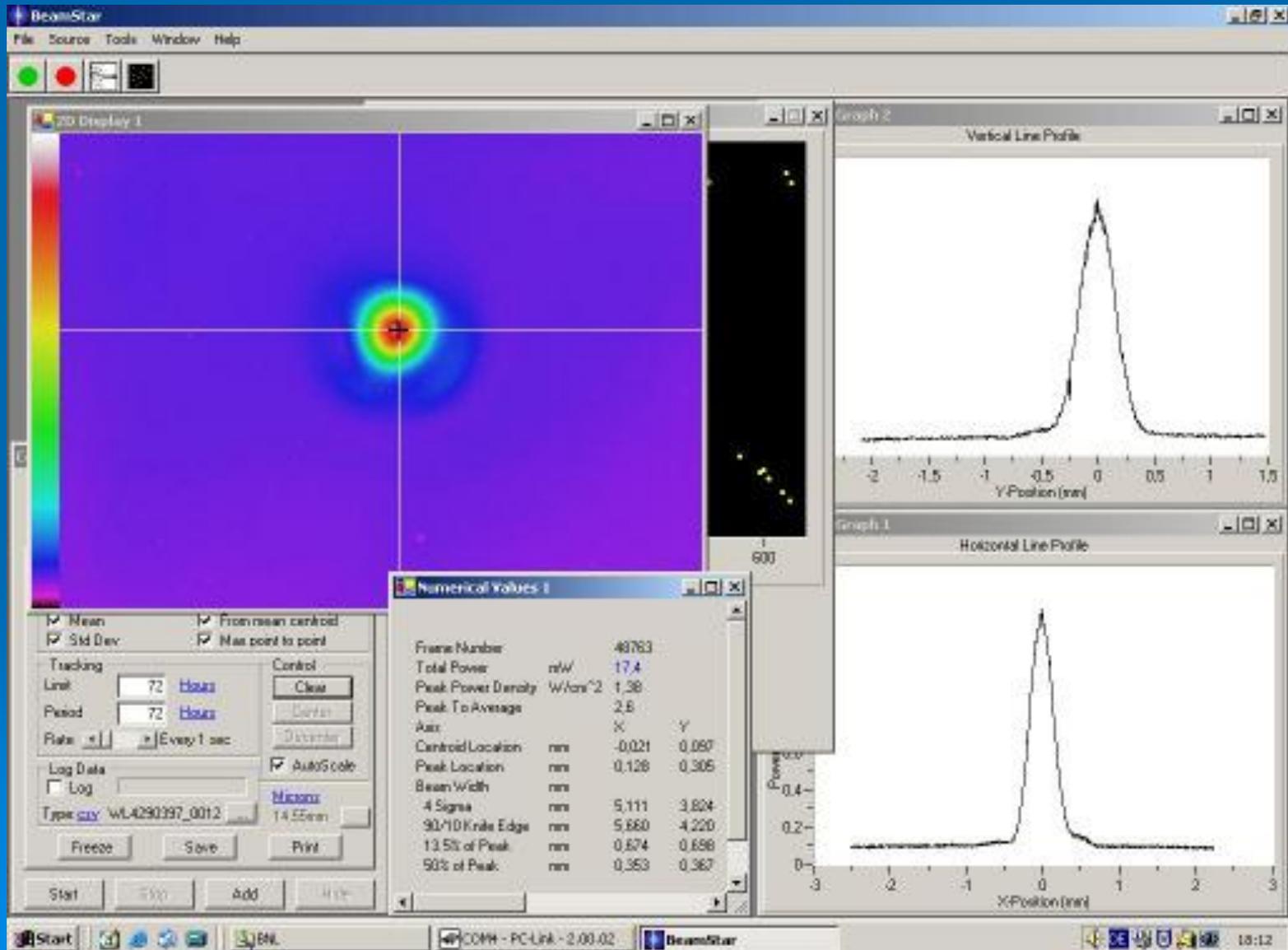
# IR image Core



Gaussian beam

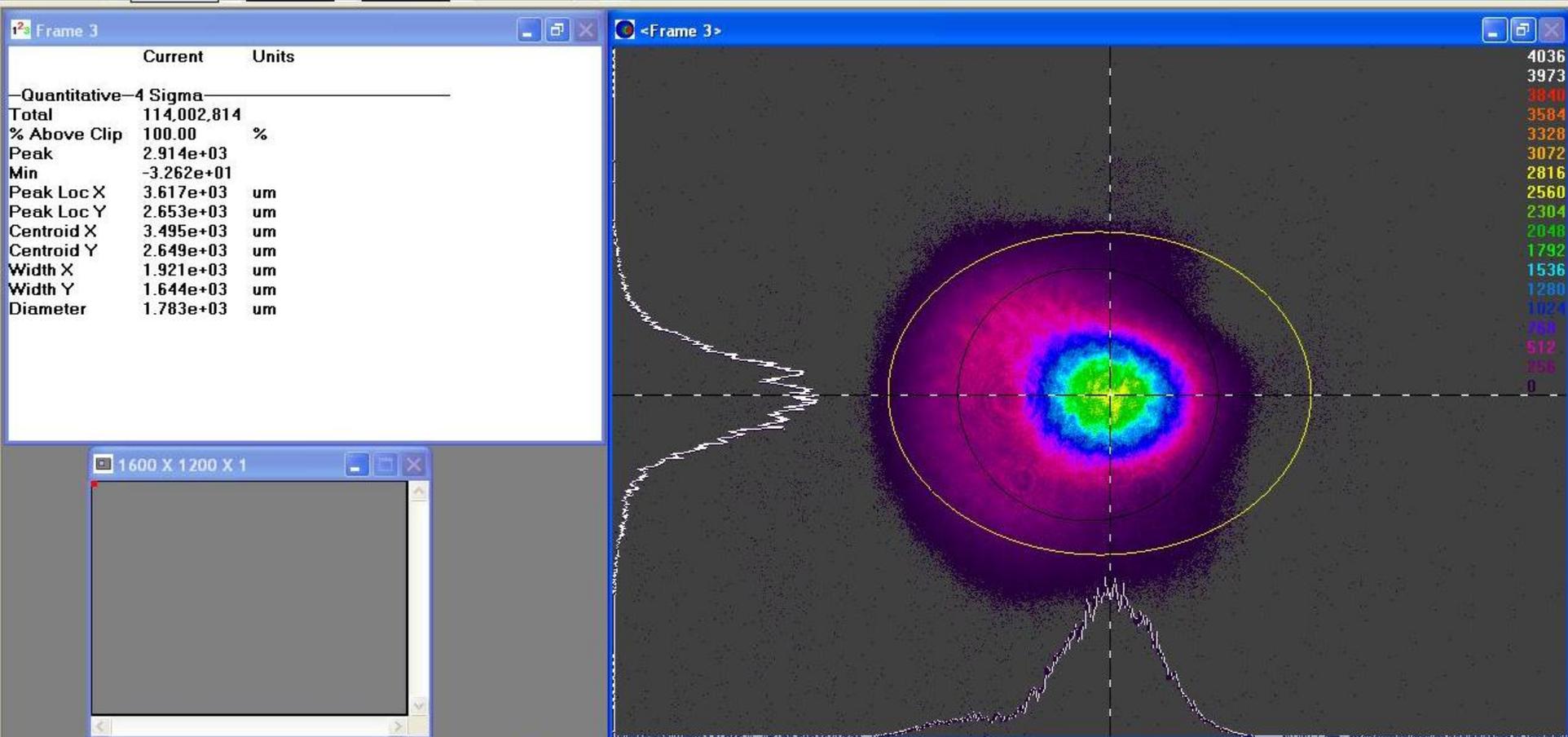
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# Green Image

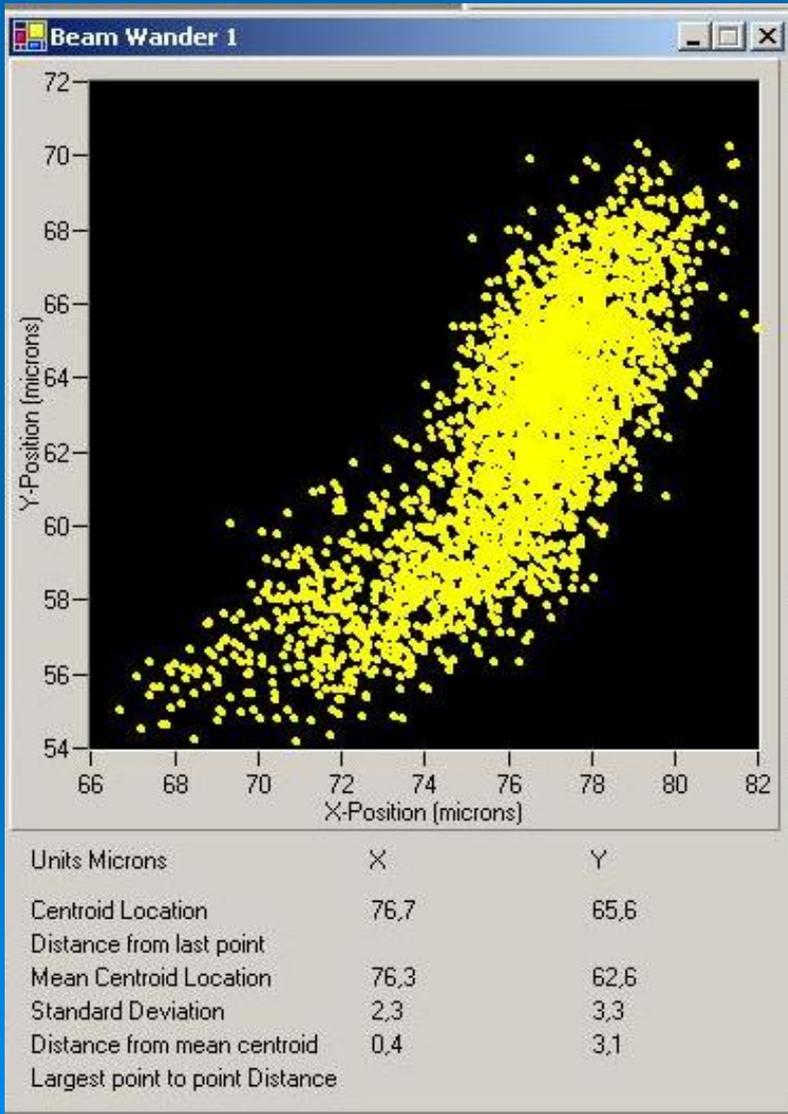


# UV image

Nonlinear process distorts the profile  
Ellipticity and nonuniformity



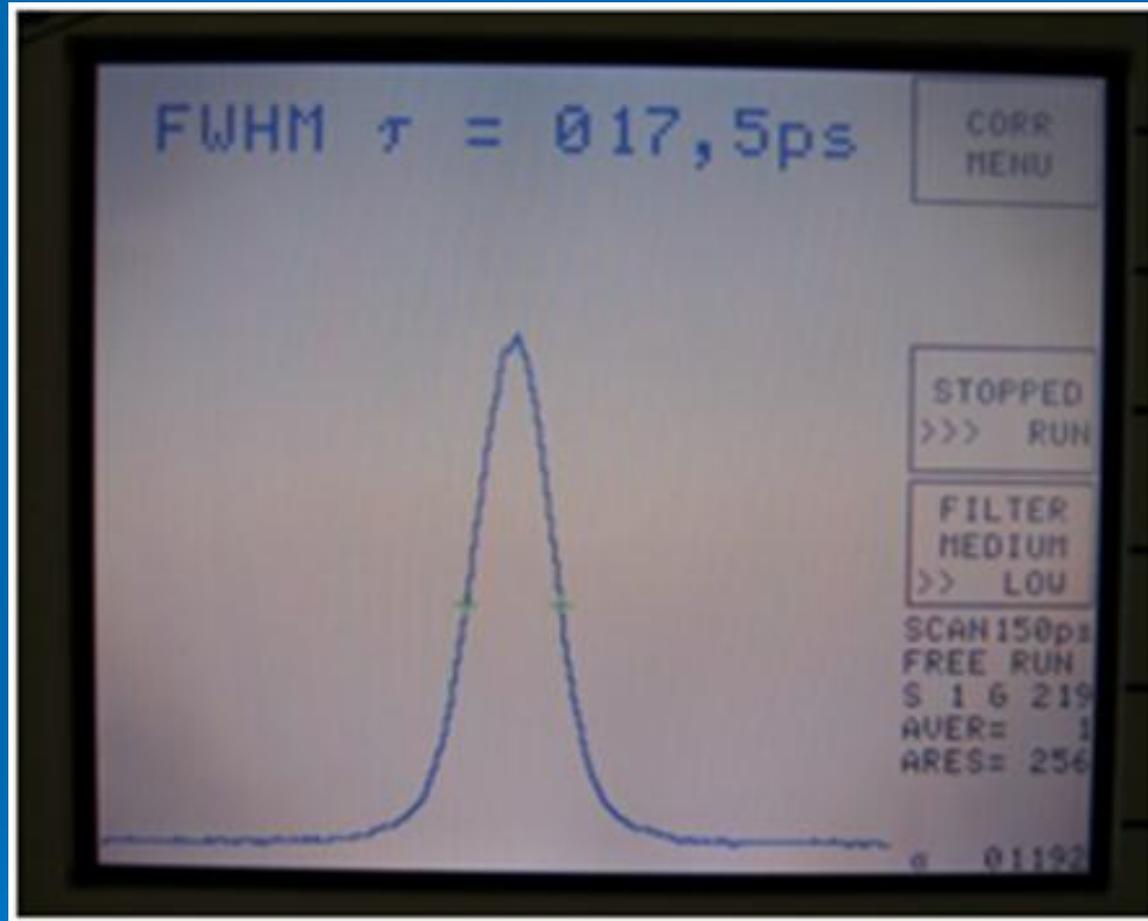
# Pointing Stability



Centroid deviation: 3.3 and 2.3  $\mu\text{m}$  in x and y respectively at 1 m from laser

Corresponds to 3.3 and 2.3  $\mu\text{rad}$  angular deviation

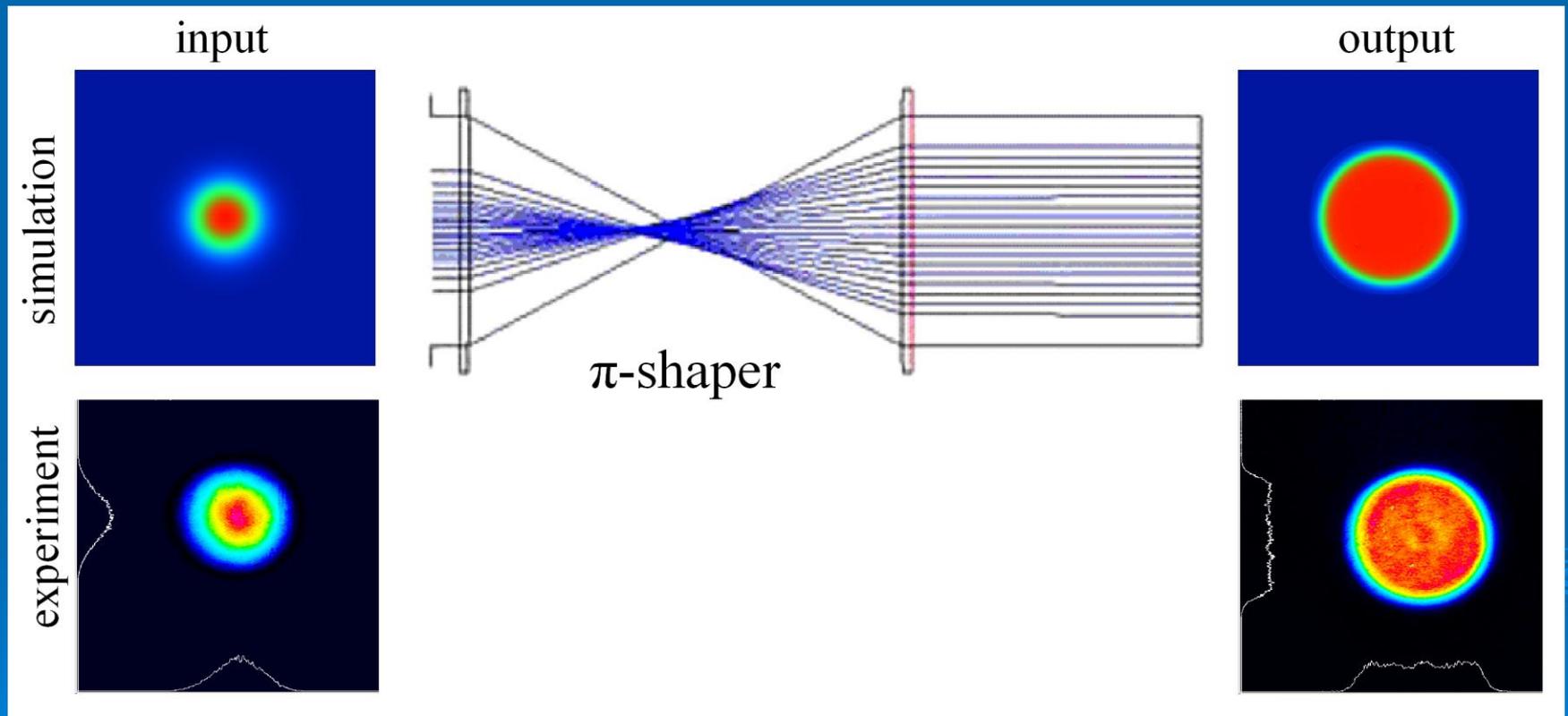
# Pulse Duration in IR



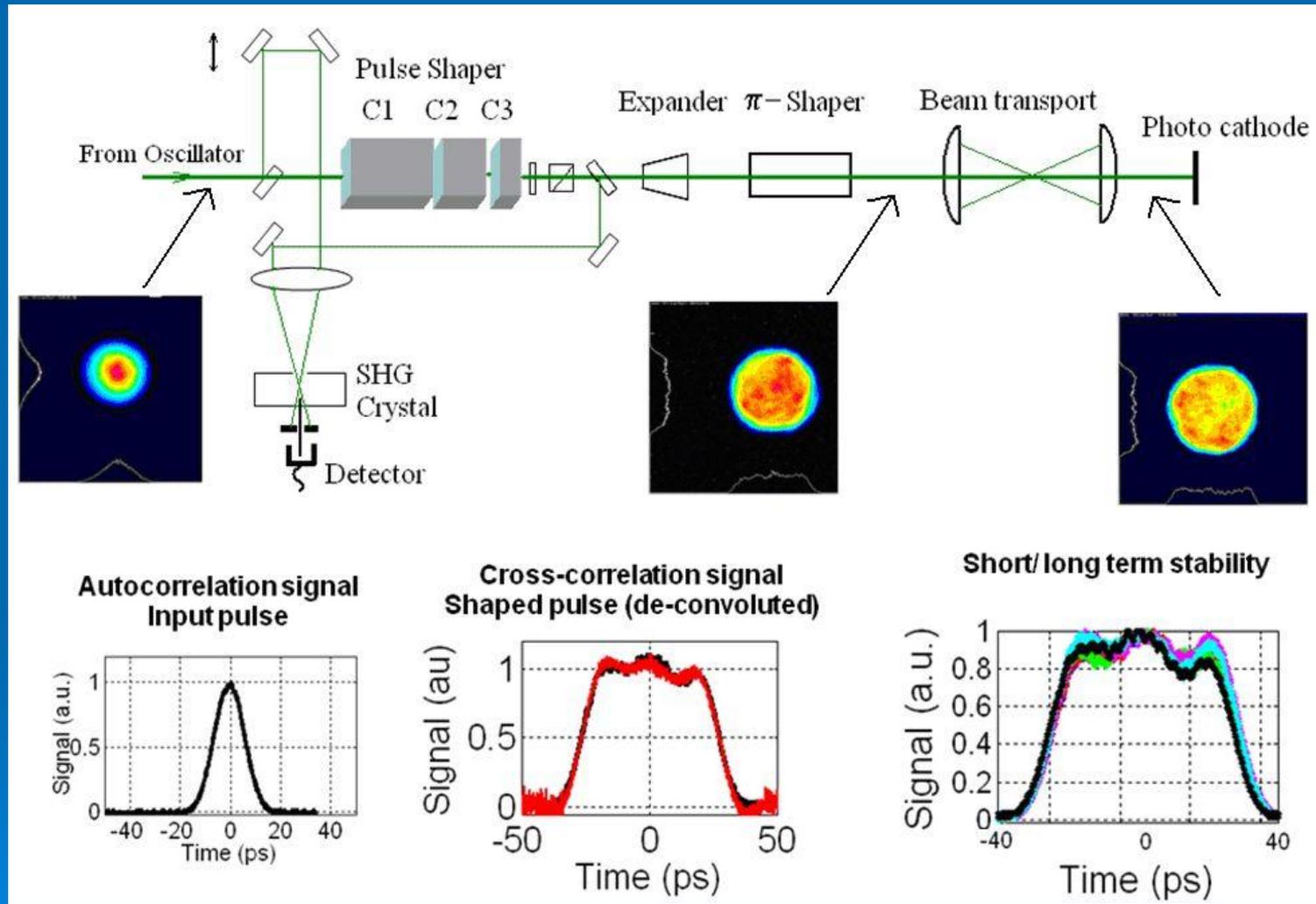
FWHM of autocorrelator trace = 17.5 ps

Corresponding FWHM for Gaussian laser pulse = 12 ps

# Spatial shaping

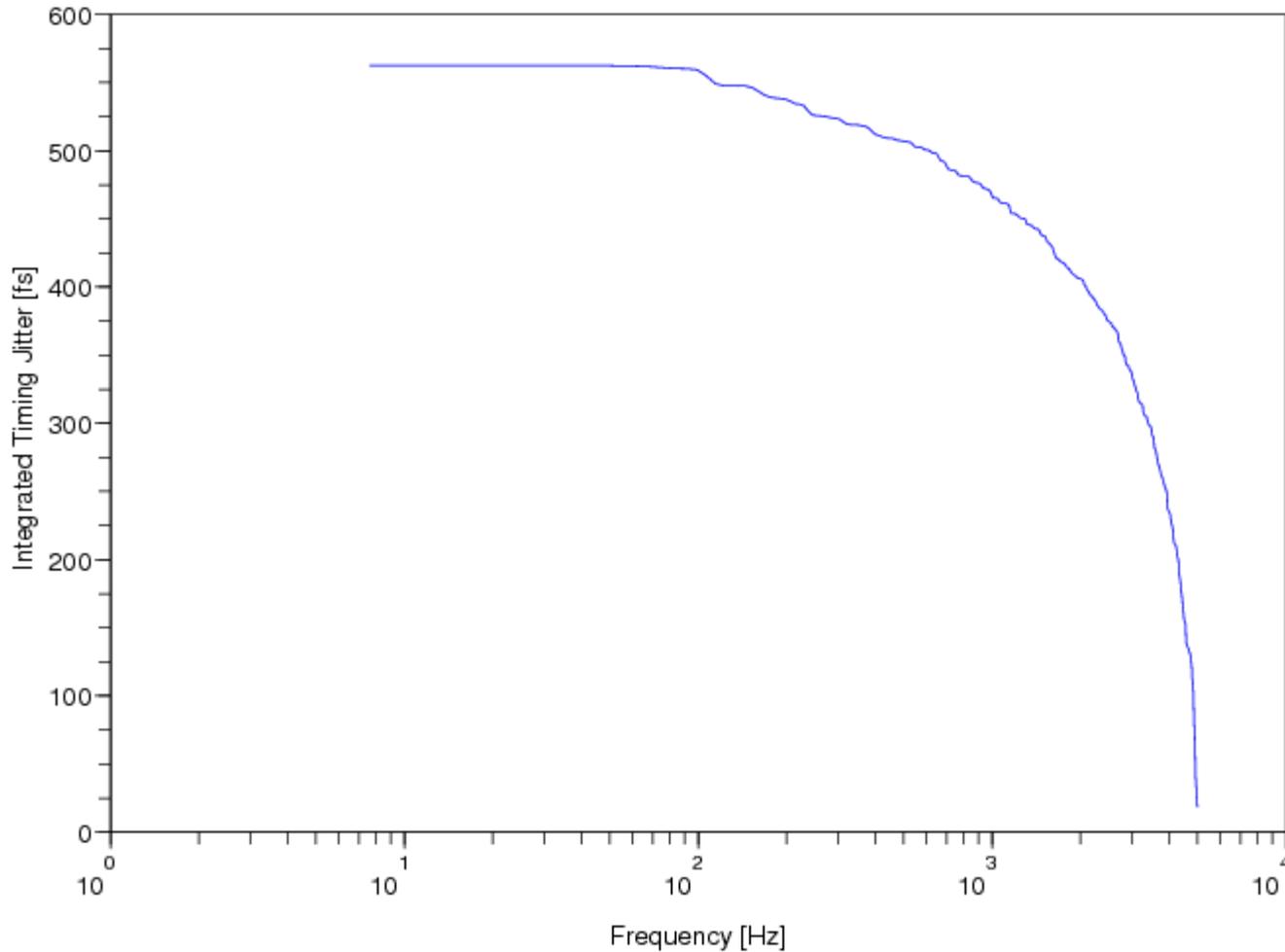


# Temporal and Spatial Shaping @ 532 nm



# Timing Jitter

Timing Jitter of Lumerica-Laser with RRE (fast PIC)  
Repetition rate lock: CG=7, FG=7.0, HF=10.0, 23.07.2008



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# Pulse Selection

